# FAIRCHILD

SEMICONDUCTOR®

# KSC5020

## High Voltage, High Quality

- + High Speed Switching :  $t_F=0.1 \mu s$
- Wide SOA



1.Base 2.Collector 3.Emitter

## **NPN Silicon Transistor**

## Absolute Maximum Ratings $T_{C}=25^{\circ}C$ unless otherwise noted

Symbol	Parameter	Value	Units
V <sub>CBO</sub>	Collector-Base Voltage	800	V
V <sub>CEO</sub>	Collector-Emitter Voltage	500	V
V <sub>EBO</sub>	Emitter-Base Voltage	7	V
I <sub>C</sub>	Collector Current (DC)	3	А
I <sub>CP</sub>	Collector Current (Pulse)	6	
I <sub>B</sub>	Base Current (DC)	1	А
P <sub>C</sub>	Collector Dissipation (T <sub>C</sub> =25°C)	40	W
TJ	Junction Temperature	150	°C
T <sub>STG</sub>	Storage Temperature	- 55 ~ 150	°C

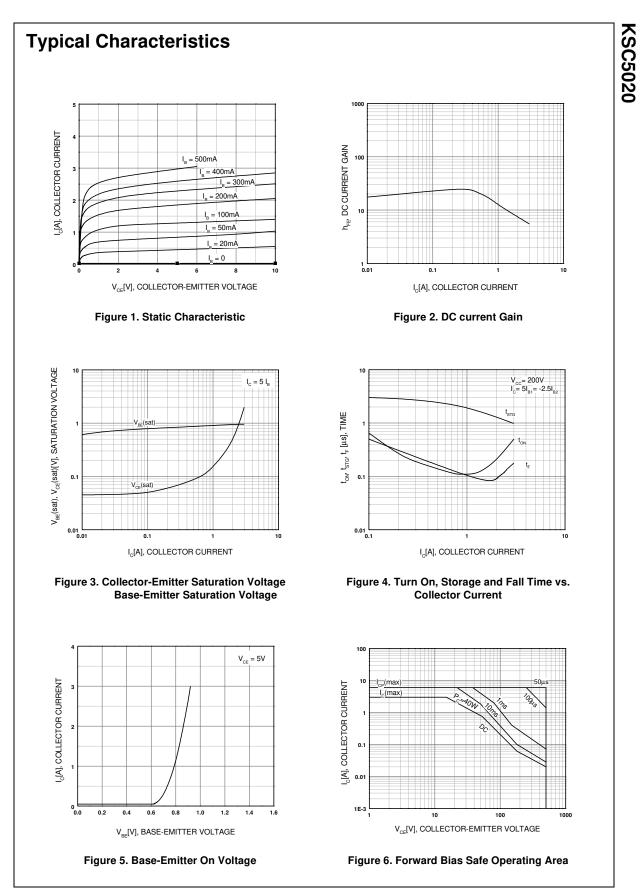
## Electrical Characteristics T<sub>C</sub>=25°C unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
BV <sub>CBO</sub>	Collector-Base Breakdown Voltage	I <sub>C</sub> = 1mA, I <sub>E</sub> = 0	800			V
BV <sub>CEO</sub> Collector-Emitter Breakdown Voltage		I <sub>C</sub> = 5mA, I <sub>B</sub> = 0	500			V
		I <sub>E</sub> = 1mA, I <sub>C</sub> = 0	7			V
V <sub>CEX</sub> (sus) Collector-Emitter Sustaining Voltage		$I_{C} = 1.5A, I_{B1}=-I_{B2}= 0.6A$ L = 2mH, Clamped	500			V
I <sub>CBO</sub> Collector Cut-off Current		V <sub>CB</sub> = 500V, I <sub>E</sub> = 0			10	μA
I <sub>EBO</sub> Emitter Cut-off Current		V <sub>EB</sub> = 5V, I <sub>C</sub> = 0			10	μA
h <sub>FE1</sub> DC Current Gain h <sub>FE2</sub>		$V_{CE} = 5V, I_C = 0.3A$ $V_{CE} = 5V, I_C = 1.5A$	15 8		50	
V <sub>CE</sub> (sat) Collector-Emitter Saturation Voltage		I <sub>C</sub> = 1.5A, I <sub>B</sub> = 0.3A			1	V
V <sub>BE</sub> (sat) Base-Emitter Saturation Voltage		I <sub>C</sub> = 1.5A, I <sub>B</sub> = 0.3A			1.5	V
C <sub>ob</sub> Output Capacitance		V <sub>CB</sub> = 10V, f = 1MHz		50		pF
f <sub>T</sub> Current Gain Bandwidth Product		V <sub>CE</sub> = 10V, I <sub>C</sub> = 0.3A		18		MHz
t <sub>ON</sub>	Turn On Time	V <sub>CC</sub> = 200V			0.5	μs
t <sub>STG</sub>	Storage Time	I <sub>C</sub> =5I <sub>B1</sub> = -2.5I <sub>B2</sub> =2A			3	μs
t <sub>F</sub>	Fall Time	R <sub>L</sub> = 100Ω			0.3	μs

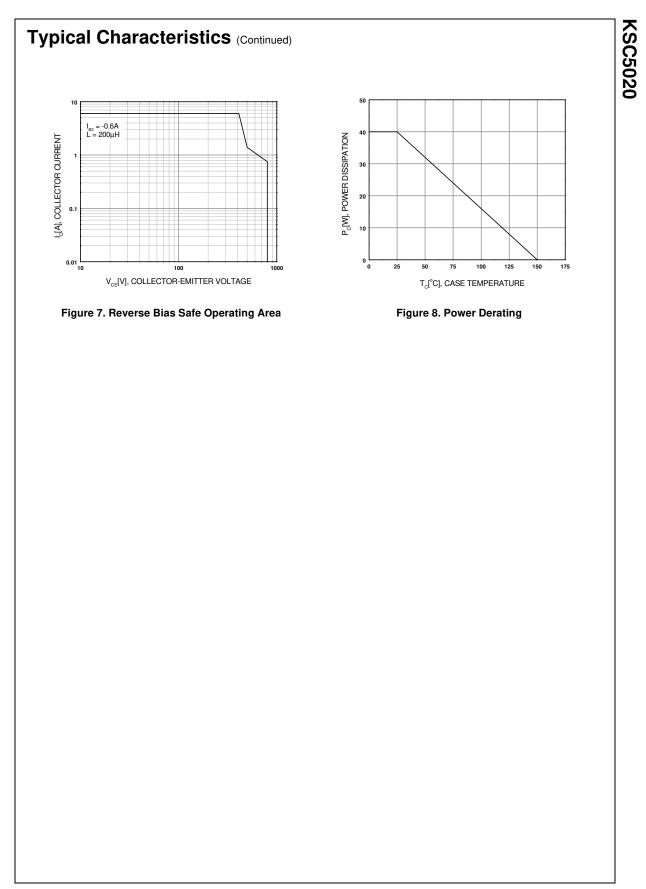
## h<sub>FE</sub> Classification

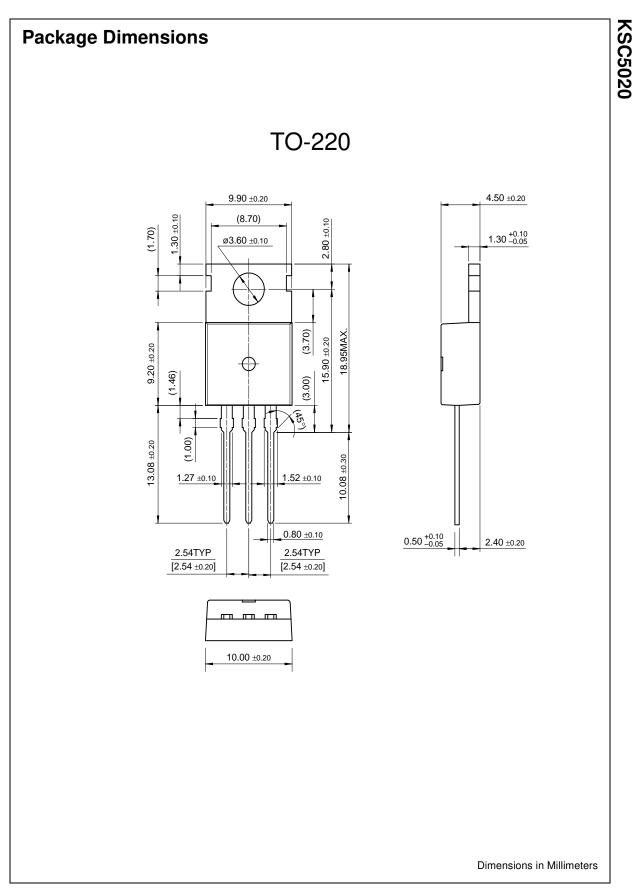
Classification	R	0	Y	
h <sub>FE1</sub>	15 ~ 30	20 ~ 40	30 ~ 50	

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Programmable Active Droop™		OPTOPLANAR™	SMART START™		

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